NSN 5962-01-434-4676

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Bgu130
Features Provided:
Burn in and monolithic and programmable and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
18 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Pal
Special Features:
Altered item make from 5962-8983903ra and program iaw spec. Vg02l012
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0